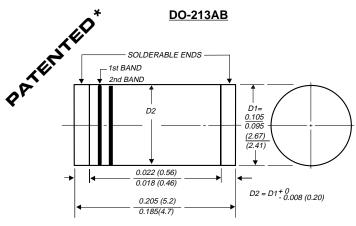
1N6478 THRU 1N6484

SURFACE MOUNT GLASS PASSIVATED JUNCTION RECTIFIER

Reverse Voltage - 50 to 1000 Volts Forward Current - 1.0 Ampere



1st band denotes type and positive end (cathode) 2nd band denotes voltage type

Ratings at 25°C ambient temperature unless otherwise specified

Dimensions in inches and (millimeters) * Glass-plastic encapsulation technique is covered by Patent No. 3,996,602 and brazed-lead assembly by Patent No. 3,930,306



FEATURES

- Plastic package has Underwriters Laboratory
 Flammability Classification 94V-0
- For surface mount applications
- High temperature metallurgically bonded construction
- Glass passivated cavity-free junction
- Capable of meeting environmental standards of MIL-S-19500
- High temperature soldering guaranteed: 450°C/5 seconds at terminals. Complete device submersible temperature of 265°C for 10 seconds in solder bath

MECHANICAL DATA

Case: JEDEC DO-213AB molded plastic over glass body **Terminals:** Plated terminals, solderable per MIL-STD-750, Method 2026

Polarity: Two bands indicate cathode end - 1st band denotes device type and 2nd band denotes repetitive peak reverse voltage rating

Mounting Position: Any Weight: 0.0046 ounce, 0.116 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Standard recovery time device: 1st band is White	SYMBOLS	1N 6478	1N 6479	1N 6480	1N 6481	1N 6482	1N 6483	1N 6484	UNITS
Polarity color bands (2nd Band)		Gray	Red	Orange	Yellow	Green	Blue	Violet	
* Maximum repetitive peak reverse voltage	Vrrm	50	100	200	400	600	800	1000	Volts
Maximum RMS voltage	Vrms	35	70	140	280	420	560	700	Volts
* Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	Volts
* Maximum average forward rectified current at	I(AV)	1.0						Amp	
 * Peak forward surge current 8.3ms single half sine-wave superimposed on rated load at T_A=75°C (JEDEC Method) 	IFSM	30.0						Amps	
* Maximum instantaneous forward voltage at 1.0A Ta=25°C T _A =75°C					1.1 1.0				Volts
* Maximum DC reverse current T _A =25°C at rated DC blocking voltage T _A =125°C		10.0 200.0						μA	
 Maximum full load reverse current, full cycle average at T_A=75°C 	IR(AV)	100.0						μA	
* Typical junction capacitance (NOTE 1)	CJ	8.0					pF		
* Maximum thermal resistance (NOTE 2) (NOTE 3)	Røja Røjt				50.0 20.0				°C/W
* Operating junction and storage temperature range	TJ, TSTG	-65 to +175						°C	

NOTES:

(2) Thermal resistance from junction to terminal, 0.24 x 0.24" (6.0 x 6.0mm) copper pads to each terminal

(3) Thermal resistance from junction to ambient, 0.24 x 0.24" (6.0 x 6.0mm) copper pads to each terminal

* JEDEC Registered Values



⁽¹⁾ Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts

RATINGS AND CHARACTERISTIC CURVES 1N6478 THRU 1N6484

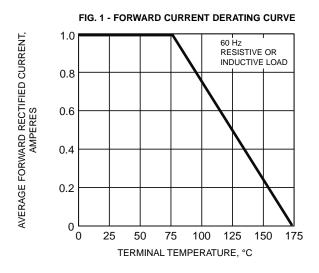


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

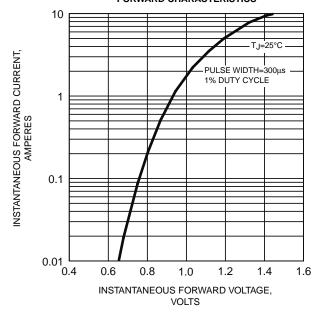
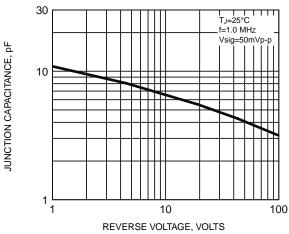


FIG. 5 - TYPICAL JUNCTION CAPACITANCE



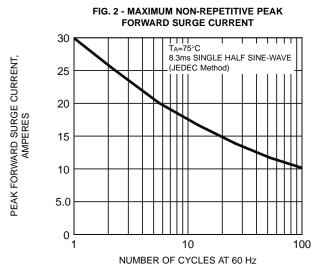
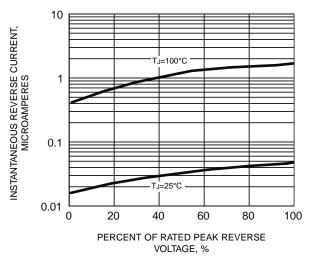
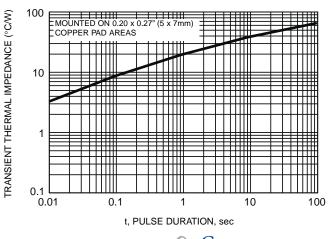


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS







GENERAL SEMICONDUCTOR Copyright © Each Manufacturing Company.

All Datasheets cannot be modified without permission.

This datasheet has been download from :

www.AllDataSheet.com

100% Free DataSheet Search Site.

Free Download.

No Register.

Fast Search System.

www.AllDataSheet.com